AMENDMENTS TO THE CLAIMS

Please amend the claims as follows:

1. (CURRENTLY AMENDED) A method for forming a pattern, comprising:

providing a substrate on which a plurality of unit panels and etching object layers on the respective unit panel areas are formed;

dividing the substrate into at least two areas;

providing a cliché on which a plurality of grooves are formed;

filling resist in the grooves; and

applying the resist-filled in the grooves of the cliché onto the etching object layer by the divided area of the substrate

transferring the resist in the grooves on a blanket applied on a surface of a printing roll by contacting and rotating the printing roll with the blanket on the cliché corresponding to the divided area of the substrate; and

applying the resist transferred on the surface of the blanket on the etching object layer.

2. (CURRENTLY AMENDED) The method of claim 1, wherein applying the resist on the etching object layer comprises:

providing a the printing roll having has a same width as that of the divided area of the substrate;

Docket No. 0630-1835P Art Unit: 1756

Page 5 of 15

transferring the resist in the groove of the cliché onto a surface of the

printing roll by contacting and rotating the printing roll on the cliché

corresponding to the divided area of the substrate; and

applying the resist transferred on the surface of the printing roll on the

etching object layer.

3. (CANCELED)

4. (CURRENTLY AMENDED) The method of claim-3_2, wherein a

length of the blanket is the same as a length of a circumference of the printing

roll, which is same as a length of the divided area of the substrate.

5. (ORIGINAL) The method of claim 1, wherein the divided area of the

substrate includes one or more unit panels.

6. (ORIGINAL) The method of claim 1, wherein the cliché is formed to

have a same size as that of the divided area of the substrate.

7. (ORIGINAL) The method of claim 1, wherein the printing roll is

formed to have a same size as that of the divided area on the substrate.

Docket No. 0630-1835P

Art Unit: 1756

Page 6 of 15

8. (ORIGINAL) The method of claim 1, wherein the etching object layer includes a metal layer.

- 9. (ORIGINAL) The method of claim 1, wherein the etching object layer includes an insulating layer comprised of SiOx or SiNx.
- 10. (ORIGINAL) The method of claim 1, wherein the etching object layer is a semiconductor layer.
- 11. (CURRENTLY AMENDED) A method for forming a pattern, comprising:

providing a substrate on which a plurality of unit panels and etching object layers on the respective unit panel areas are formed;

dividing the substrate into a plurality of divided areas so as to include at least one or more unit panels;

providing a cliché on which a plurality of grooves are formed;

filling resist in the grooves of the cliché;

providing a <u>blanket on a printing</u> roll having a same width as that of the divided area of the substrate;

Docket No. 0630-1835P

Art Unit: 1756

Page 7 of 15

transferring the resist filled in the groove of the cliché onto a surface of

the <u>blanket on the</u> printing roll by contacting and rotating the printing roll <u>with</u>

the blanket on the cliché; and

applying the resist transferred on the surface of the printing roll-blanket

on the etching object layer.

12. (CURRENTLY AMENDED) The method of claim 11, wherein

applying the resist on the etching object layer is performed by contacting the

resist transferred on the surface of the blanket on the printing roll on the

substrate and by rotating the printing roll with the blanket.

13. (ORIGINAL) The method of claim 11, wherein the divided area of

the substrate includes at least one unit panel.

14. (ORIGINAL) The method of claim 11, wherein the etching object

layer includes a metal layer.

15. (ORIGINAL) The method of claim 11, wherein the etching object

layer comprises an insulating layer comprised of SiOx or SiNx.

Docket No. 0630-1835P

Art Unit: 1756 Page 8 of 15

16. (ORIGINAL) The method of claim 11, wherein the etching object layer is a semiconductor layer.

17. (CURRENTLY AMENDED) A pattern, which has been formed by:

providing a substrate on which a plurality of unit panels and etching object layers on the respective unit panel areas are formed;

dividing the substrate into at least two areas;

providing a cliché on which a plurality of grooves are formed;

filling resist in the grooves; and

applying the resist filled in the grooves of the cliché onto the etching object layer by the divided area of the substrate

transferring the resist in the grooves on a blanket applied on a surface of a printing roll by contacting and rotating the printing roll with the blanket on the cliché corresponding to the divided area of the substrate; and

applying the resist transferred on the surface of the blanket on the etching object layer.

18. (CURRENTLY AMENDED) A pattern, which has been formed by:

providing a substrate on which a plurality of unit panels and etching object layers on the respective unit panel areas are formed;

Docket No. 0630-1835P

Art Unit: 1756 Page 9 of 15

dividing the substrate into a plurality of divided areas so as to include at

least one or more unit panels;

providing a cliché on which a plurality of grooves are formed;

filling resist in the grooves of the cliché;

providing a blanket on a printing roll having a same width as that of the

divided area of the substrate;

transferring the resist filled in the groove of the cliché onto a surface of

the <u>blanket on the printing</u> roll by contacting and rotating the printing roll <u>with</u>

the blanket on the cliché; and

applying the resist transferred on the surface of the printing roll blanket

on the etching object layer.

19. (NEW) A method for forming a resist pattern, comprising:

transferring a resist material from one or more grooves of a cliché onto a

blanket; and

transferring the resist material from the blanket onto a surface of an

etching object layer to form the resist pattern.

Docket No. 0630-1835P

Art Unit: 1756

Page 10 of 15

20. (NEW) The method of claim 19, wherein the step of transferring the

resist material from the one or more grooves of the cliché onto the blanket

comprises:

applying the blanket onto a surface of a printing roll; and

rolling the printing roll with the blanket on the cliché.

21. (NEW) The method of claim 20, wherein the step of transferring the

resist material from the blanket onto the surface of the etching object layer to

form the resist pattern comprises:

rolling the printing roll with the blanket with the resist material thereon

on the surface of the etching object layer.

22. (NEW) The method of claim 20, wherein size and shape of the

blanket, size and shape of the cliché, and size and shape of a surface area of

the printing roll are all substantially the same.

23. (NEW) The method of claim 22, wherein

the printing roll is cylindrical,

a height of the printing roll is substantially equal to a height of the

blanket, and

Docket No. 0630-1835P

Art Unit: 1756 Page 11 of 15

a circumference of the printing roll is substantially equal to a length of

the blanket.

24. (NEW) The method of claim 22, wherein

the object layer is divided into a plurality of divided areas, and

the size and shape of the blanket is substantially the same as a size and

shape of a sum of one or more divided areas of the plurality of divided areas.

25. (NEW) The method of claim 24, wherein size and shape of each

divided area of the object layer is substantially the same in size and shape as

each of the other divided areas.

26. (NEW) The method of claim 24, wherein the area of the blanket is

less than an area of the etching object layer.

27. (NEW) The method of claim 26, wherein the area of the etching

object layer is substantially a whole multiple of the area the blanket.